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FIN1215 / FIN1216 / FIN1217/ FIN1218 LVDS 21-Bit Serializers / De-Serializers

Features

- Low Power Consumption
- 20MHz to 85MHz Shift Clock Support
- 50% Duty Cycle on the Clock Output of Receiver
- ±1V Common-mode Range ~1.2V
- Narrow Bus Reduces Cable Size and Cost
- High Throughput: 1.785Gbps
- Up to 595Mbps per Channel
- Internal PLL with No External Components
- Compatible with TIA/EIA-644 Specification
- Offered in 48-lead TSSOP Packages

Description

The FIN1217 and FIN1215 transform 21-bit wide parallel LVTTL (Low-Voltage TTL) data into three serial LVDS (Low-Voltage Differential Signaling) data streams. A phase-locked transmit clock is transmitted in parallel with the data stream over a separate LVDS link. Every cycle of transmit clock, 21 bits of input LVTTL data are sampled and transmitted.

The FIN1216 and FIN1218 receives and converts the three serial LVDS data streams back into 21 bits of LVTTL data. Table 1 provides a matrix summary of the serializers and de-serializers available. For the FIN1217, at a transmit clock frequency of 85MHz, 21 bits of LVTTL data are transmitted at a rate of 595Mbps per LVDS channel.

These chipsets solve EMI and cable size problems associated with wide and high-speed TTL interfaces.

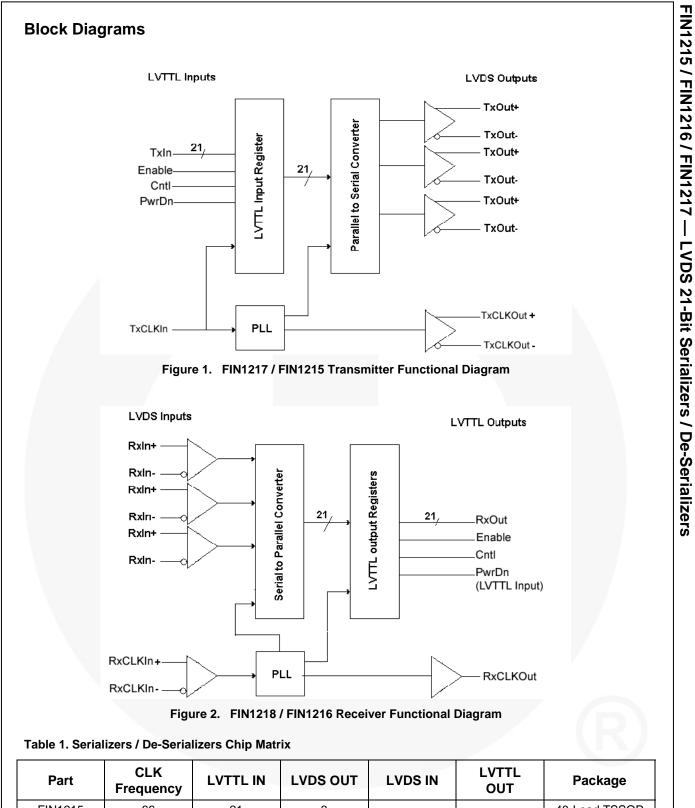
Ordering Information

Part Number	Operating Temperature Range	Eco Status	Package	Packing Method				
FIN1215MTDX								
FIN1216MTDX								
FIN1217MTDX	-40 to + 85°C	RoHS	RoHS	RoHS	RoHS	RoHS	48-Lead Thin Shrink Small Outline Package (TSSOP)	Tape and Reel
FIN1218MTDX (Preliminary)								

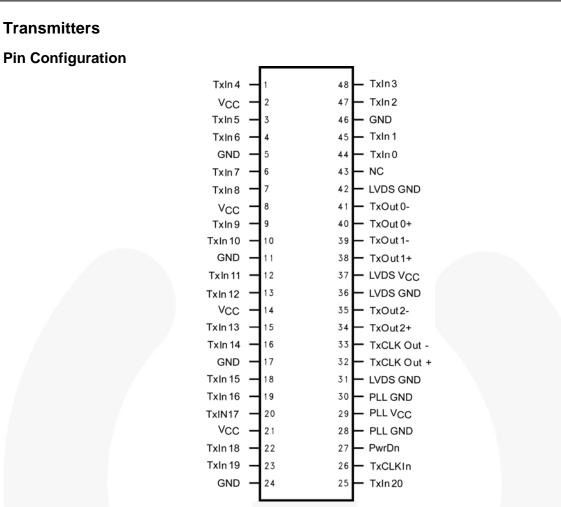
Ø For Fairchild's definition of Eco Status, please visit: <u>http://www.fairchildsemi.com/company/green/rohs_green.html</u>.







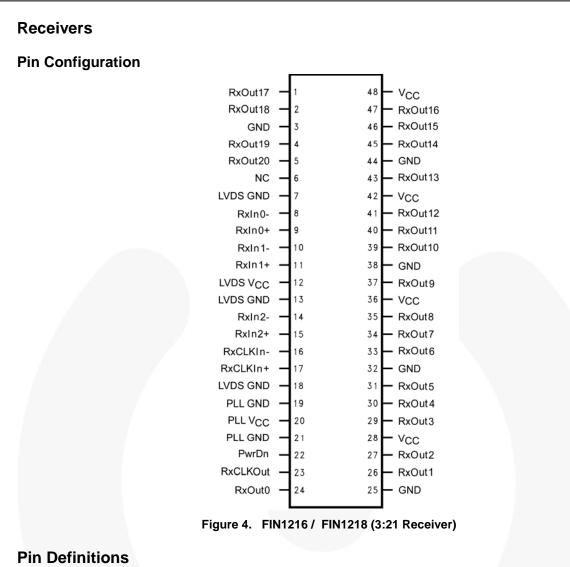
Part	CLK Frequency	LVTTL IN	LVDS OUT	LVDS IN	LVTTL OUT	Package
FIN1215	66	21	3			48-Lead TSSOP
FIN1216	66			3	21	48-Lead TSSOP
FIN1217	85	21	3			48-Lead TSSOP
FIN1218	85			3	21	48-Lead TSSOP





Pin Definitions

Pin Names	l/O Type	# of Pins	Description of Signals	
TxIn	I	21	LVTTL Level Inputs	
TxCKLIn	I	1	LVTTL Level Clock Input; the rising edge is for data strobe	
TxOut+	0	3	Positive LVDS Differential Data Output	
TxOut	0	3	Negative LVDS Differential Data Output	
TxCLKOut+	0	1	Positive LVDS Differential Clock Output	
TxCLKOut-	0	1	Negative LVDS Differential Clock Output	
/PwrDn	I	1	LVTTL Level Power-Down Input; assertion (LOW) puts the outputs in high- impedance state	
PLL V _{CC}	I	1	Power Supply Pin for LVDS Outputs	
PLL GND	I	2	Ground Pins for PLL	
LVDS V _{CC}	I	1	Power Supply Pins for LVDS Outputs	
LVDS GND	I	3	Ground Pin for LVDS Outputs	
Vcc	I	4	Power Supply Pins for LVTTL Inputs	
GND	I	5	Ground Pins for LVTTL Inputs	
NC			No Connect	



Pin Names	l/O Type	# of Pins	Description of Signals
RxIn	I	3	Negative LVDS Differential Data Output
RxIn+	I	3	Positive LVDS Differential Data Output
RxCLKIn-	I	1	Negative LVDS Differential Clock Output
RxCLKIn+	I	1	Positive LVDS Differential Clock Output
RxOut-	0	21	LVTTL Level Data Outputs Goes HIGH for /PwrDn LOW
RxCLKOut	0	1	LVTTL Level Clock Output
/PwrDn	I	1	LVTTL Level Input; Refer to Transmitter and Receiver Power-up and Power-down Operation Truth Table
PLL V _{CC}	I	1	Power Supply Pin for PLL
PLL GND	I	2	Ground Pins for PLL
LVDS V _{CC}	I	1	Power Supply Pins for LVDS Inputs
LVDS GND	I	3	Ground Pin for LVDS Inputs
Vcc	I	4	Power Supply Pins for LVTTL Outputs
GND	I	5	Ground Pins for LVTTL Outputs
NC			No Connect

Truth Tables

Transmitter

	Inputs	Outputs			
TxIn	TxCLKIn	PwrDn ⁽¹⁾	TxOut±	TxCLKOut±	
Active	Active	HIGH	LOW / HIGH	LOW / HIGH	
Active	LOW / HIGH High Impedance	HIGH	LOW / HIGH	Don't Care ⁽²⁾	
Floating	Active	HIGH	LOW	LOW / HIGH	
Floating	Floating	HIGH	LOW	Don't Care ⁽²⁾	
Don't Care	Don't Care	LOW	High Impedance	High Impedance	

Notes:

1. The outputs of the transmitter or receiver remain in a high-impedance state until V_{CC} reaches 2V.

2. TxCLKOut± settles at a free running frequency when the part is powered up, PwrDn is HIGH and the TxCLKIn is a steady logic level LOW / HIGH / high-impedance.

Receiver

	Inputs		Out	puts
RxIn±	RxCLKIn±	/PwrDn ⁽³⁾	RxOut	RxCLKOut
Active	Active	HIGH	LOW / HIGH	LOW / HIGH
Active	Failsafe Condition ⁽⁴⁾	HIGH	Last Valid State	HIGH
Failsafe Condition ⁽⁴⁾	Active	HIGH	HIGH	LOW / HIGH
Failsafe Condition ⁽⁴⁾	Failsafe Condition ⁽⁴⁾	HIGH	Last Valid State ⁽⁵⁾	HIGH
Don't Care	Don't Care	LOW	LOW	HIGH

Notes:

3. The outputs of the transmitter or receiver remain in a high-impedance state until V_{CC} reaches 2V.

4. Failsafe condition is defined as the input being terminated and un-driven, shorted, or open.

5. If RxCLKIn± is removed prior to the RxIn± date being removed, RxOut is the last valid state. If RxIn± data is removed prior to RxCLKIn± being removed, RxOut is HIGH.

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Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Par	Min.	Max.	Unit	
V _{CC}	Power Supply Voltage	-0.3	+4.6	V	
V _{TTL}	TTL/CMOS Input/Output Voltage		-0.5	+4.6	V
V _{LVDS}	LVDS Input/Output Voltage		-0.3	+4.6	V
I _{OSD}	LVDS Output Short-Circuit Current			Continuous	
T _{STG}	Storage Temperature Range		-65	+150	°C
TJ	Maximum Junction Temper		+150	°C	
TL	Lead Temperature			+260	°C
	Human Body Model, JESD22-A114	LVDS I/O to Ground		10.0	kV
ESD	(1.5kΩ, 100pF)	All Pins (FIN1215, FIN1217)		6.5	ΝV
	Machine Model, JESD22-A115, 0Ω, 200pF	FIN1215, FIN1217 Only		>400	V

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{CC}	Supply Voltage	3.0	3.6	V
T _A	Operating Temperature	-40	+85	°C
V _{CCNPP}	Maximum Supply Noise Voltage ⁽⁶⁾		100	mV_{PP}

Note:

6. $100mV V_{CC}$ noise should be tested for frequency at least up to 2MHz. All the specifications should be met under such a noise level.

Transmitter DC Electrical Characteristics

Typical values are at $T_A=25$ °C and with $V_{CC}=3.3V$; minimum and maximum are at over supply voltages and operating temperatures ranges, unless otherwise specified.

Symbol	Parameter	Test Con	ditions	Min.	Тур.	Max.	Units
Transmitte	r LVTTL Input Characteristics						
VIH	Input High Voltage			2.0		Vcc	V
V _{IL}	Input Low Voltage			GND		0.8	V
VIK	Input Clamp Voltage	I _{IK} =-18mA			-0.79	-1.50	V
I _{IN}	Input Current	V _{IN} =0.4V to 4.	6V		1.8	10.0	
IN		V _{IN} =GND		-10.0	0		μA
Transmitte	r LVDS Output Characteristics ⁽⁷⁾						
V _{OD}	Output Differential Voltage		250		450	mV	
ΔV_{OD}	V _{OD} Magnitude Change from Differential LOW-to-HIGH	− R∟=100Ω, Figure 4				35	mV
Vos	Offset Voltage	$R_{L}=100\Omega$, Figu	1.125	1.250	1.375	V	
ΔV_{OS}	Offset Magnitude Change from Differential LOW-to-HIGH			25		mV	
l _{os}	Short-Circuit Output Current	V _{OUT} =0V			-3.5	-5.0	mA
I _{OZ}	Disabled Output Leakage Current	D _O =0V to 4.6V /PwrDn=0V	',		±1.0	±10.0	μΑ
Transmitte	r Supply Current				•	•	
			33MHz		28.0	46.2	
	21:3 Transmitter Power Supply Current for Worst-Case Pattern with Load ^(8, 9)	R _L =100Ω,	40MHz		29.0	51.7	
I _{CCWT}	for Worst-Case Pattern with Load ^(8, 9)	Figure 7	65MHz		34.0	57.2	mA
			85MHz ⁽¹⁰⁾		39.0	62.7	
ICCPDT	Powered-Down Supply Current	/PwrDn=0.8V			10.0	55.0	μA

Notes:

 Positive current values refer to the current flowing into device and negative values means current flowing out of pins. Voltages are referenced to ground unless otherwise specified (except ΔV_{OD} and V_{OD}).

8. The power supply current for both transmitter and receiver can be different with the number of active I/O channels.

The 16-grayscale test pattern tests device power consumption for a "typical" LCD display pattern. The test
pattern approximates signal switching needed to produce groups of 16 vertical strips across the display.
 FIN1217 only.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{TCP}	Transmit Clock Period	Figure 10	11.76	Т	50.00	ns
t _{TCH}	Transmit Clock (TxCLKIn) HIGH Time		0.35	0.50	0.65	Т
t _{TCL}	Transmit Clock LOW Time		0.35	0.50	0.65	Т
t _{CLKT}	TxCLKIn Transition Time (Rising and Falling)	10% to 90% Figure 11	1.0		6.0	ns
t _{JIT}	TxCLKIn Cycle-to-Cycle Jitter				3.0	ns
t _{XIT}	TxIn Transition Time		1.5		6.0	ns
LVDS Tra	ansmitter Timing Characteristics					
t _{TLH}	Differential Output Rise Time (20% to 80%)	F i a		0.75	1.50	ns
t⊤⊣∟	Differential Output Fall Time (80% to 20%)	Figure 8		0.75	1.50	ns
t _{STC}	TxIn Setup to TxCLNIn	Figure 10	2.5			ns
t _{HTC}	TxIn Holds to TCLKIn	f=85MHz FIN1217 only	0			ns
t _{TPDD}	Transmitter Power-Down Delay	Figure 17 ⁽¹¹⁾			100	ns
tтсср	Transmitter Clock Input to Clock Output Delay	Figure 13 T _A =25°C, V _{CC} =3.3V	2.8	5.5	6.8	ns
Transmit	ter Output Data Jitter (f=40 MHz) ⁽¹²⁾					
t _{TPPB0}	Transmitter Output Pulse Position of Bit 0		-0.25	0	0.25	ns
t _{TPPB1}	Transmitter Output Pulse Position of Bit 1		a-0.25	а	a+0.25	ns
t _{TPPB2}	Transmitter Output Pulse Position of Bit 2	Figure 20	2a-0.25	2a	2a+0.25	ns
t _{TPPB3}	Transmitter Output Pulse Position of Bit 3	$a = \frac{1}{f \times 7}$	3a-0.25	3a	3a+0.25	ns
t _{TPPB4}	Transmitter Output Pulse Position of Bit 4	f×7	4a-0.25	4a	4a+0.25	ns
t _{TPPB5}	Transmitter Output Pulse Position of Bit 5		5a-0.25	5a	5a+0.25	ns
t _{TPPB6}	Transmitter Output Pulse Position of Bit 6		6a-0.25	6a	6a+0.25	ns
Transmitt	er Output Data Jitter (f=65 MHz) ⁽¹²⁾					
t _{TPPB0}	Transmitter Output Pulse Position of Bit 0		-0.2	0	0.2	ns
t _{TPPB1}	Transmitter Output Pulse Position of Bit 1		a-0.2	а	a+0.2	ns
t _{TPPB2}	Transmitter Output Pulse Position of Bit 2	Figure 20	2a-0.2	2a	2a+0.2	ns
t _{TPPB3}	Transmitter Output Pulse Position of Bit 3	$a = \frac{1}{f \times 7}$	3a-0.2	За	3a+0.2	ns
t _{TPPB4}	Transmitter Output Pulse Position of Bit 4		4a-0.2	4a	4a+0.2	ns
t _{TPPB5}	Transmitter Output Pulse Position of Bit 5		5a-0.2	5a	5a+0.2	ns
t _{TPPB6}	Transmitter Output Pulse Position of Bit 6		6a-0.2	6a	6a+0.2	ns

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FIN1216 / F
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LVDS 21-Bit S
: Serializer
's / De-Serializers

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Transmitte	r Output Data Jitter (f=85 MHz, FIN1217 only) ⁽¹²⁾				
t _{TPPB0}	Transmitter Output Pulse Position of Bit 0		-0.2	0	0.2	ns
t _{TPPB1}	Transmitter Output Pulse Position of Bit 1	-	a-0.2	а	a+0.2	ns
t _{TPPB2}	Transmitter Output Pulse Position of Bit 2	$ \begin{array}{c} \text{only}^{(12)} \\ 0 \\ 1 \\ 2 \\ 3 \\ 4 \\ 5 \\ 6 \\ \end{array} $ Figure 20 $a = \frac{1}{f \times 7}$ $f = 40 \text{MHz}$	2a-0.2	2a	2a+0.2	ns
t _{TPPB3}	Transmitter Output Pulse Position of Bit 3		3a-0.2	3a	3a+0.2	ns
t _{TPPB4}	Transmitter Output Pulse Position of Bit 4		4a-0.2	4a	4a+0.2	ns
t _{TPPB5}	Transmitter Output Pulse Position of Bit 5		5a-0.2	5a	5a+0.2	ns
t _{TPPB6}	Transmitter Output Pulse Position of Bit 6		6a-0.2	6a	6a+0.2	ns
		f=40MHz		350	370	
t _{JCC}	Transmitter Clock Out Jitter, Cycle-to cycle	f=65MHz		210	230	ps
	Figure 23			2 a a+(.2 2a 2a+ .2 3a 3a+ .2 4a 4a+ .2 5a 5a+ .2 6a 6a+ .350 37 210 23	150	μs
t _{TPLLS}	Transmitter Phase Lock Loop Set Time ⁽¹³⁾	Figure 15 ⁽¹²⁾			10.0	ms

Notes:

Outputs of all transmitters stay in 3-STATE until power reaches 2V. Clock and data output begins to toggle 10ms after V_{CC} reaches 3V and /PwrDn pin is above 1.5V.
 This output data pulse position works for both transmitters with 21 TTL inputs, except the LVDS output bit mapping difference (see Figure 19). Figure 20 shows the skew between the first data bit and clock output. A two-bit cycle delay is guaranteed when the MSB is output from transmitter.

13. This jitter specification is based on the assumption that PLL has a reference clock with cycle-to-cycle input jitter of less than 2ns.

Receiver DC Electrical Characteristics

Typical values are at T_A=25°C and with V_{CC}=3.3V. Positive current values refer to the current flowing into device and negative values means current flowing out of pins. Voltages are referenced to ground unless otherwise specified (except ΔV_{OD} and V_{OD}). Minimum and maximum values are at over supply voltage and operating temperature ranges unless otherwise specified.

Symbol	Parameter	Conditions		Min.	Тур.	Max.	Units
LVTTL/CM	IOS DC Characteristics						
V _{IH}	Input High Voltage			2.0		V _{CC}	V
VIL	Input Low Voltage			GND		0.8	V
V _{OH}	Output High Voltage	I _{OH} =-0.4mA		2.7	3.3		V
V _{OL}	Output Low Voltage	I _{OL} =2mA				0.3	V
VIK	Input Clamp Voltage	I _{IK} =-18mA				-1.5	V
I _{IN}	Input Current	V _{IN} =0V to 4.6V		-10		10	μA
I _{OFF}	Input/Output Power-Off Leakage Current	V _{CC} =0V, All LVTTL Inputs/Outputs 0V to 4.6V				±10	μA
los	Output Short-Circuit Current	V _{OUT} =0V			-60	-120	μA
Receiver	LVDS Input Characteristics						
Vтн	Differential Input Threshold HIGH	Figure 6, Table 2				100	mV
V _{TL}	Differential Input Threshold LOW	Figure 6, Table 2		-100			mV
VICM	Input Common Mode Range	Figure 6, Table 2		0.05		2.35	V
	In put Current	V _{IN} =2.4V, V _{CC} =3.6V or 0V				±10.0	μA
I _{IN}	Input Current	V _{IN} =0V, V _{CC} =3.6V or 0V				±10.0	
Receiver	Supply Current						
	3:21 Receiver Power Supply Current for Worst Case Pattern with Load ⁽¹⁴⁾	33	BMHz			66	mA
		40)MHz		56	74	
ICCWR		C _L =8pF, Figure 7	5MHz		75	102	
		85MHz ⁽¹⁵⁾	5MHz ⁽¹⁵⁾		92	125	
I _{CCPDR}	Powered Down Supply Current	/PwrDn=0.8V (RxOut stays LOW)			NA	400	μA

Notes:

14. The power supply current for the receiver can be different due to the number of active I/O channels.

15. 85MHz specification for FIN1218 only.

Receiver AC Electrical Characteristics

Values are at over supply voltages and operating temperatures, unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{RCOL}	RxCLKOut LOW Time		10.0	11.0		ns
t _{RCOH}	RxCLKOut HIGH Time	Figure 12	10.0	12.2		ns
t _{RSRC}	RxOut Valid Prior to RxCLKOut	Rising Edge Strobe	6.5	11.6		ns
t _{RHRC}	RxOut Valid After RxCLKOut		6.0	11.6		ns
t _{RCOP}	Receiver Clock Output (RxCLKOut) Period		15.0	Т	50.0	ns
t _{RCOL}	RxCLKOut LOW Time	Figure 12	5.0	7.8	9.0	ns
t _{RCOH}	RxCLKOut HIGH Time	Rising Edge Strobe	5.0	7.3	9.0	ns
t _{RSRC}	RxOut Valid Prior to RxCLKOut		4.5	7.7		ns
t _{RHRC}	RxOut Valid After RxCLKOut		4.0	8.4		ns
t _{RCOP}	Receiver Clock Output (RxCLKOut) Period		11.76	Т	50.00	ns
t _{RCOL}	RxCLKOut LOW Time	Figure 12 Rising Edge Strobe f=85MHz FIN1218 only	4.0	6.3	6.0	ns
t _{RCOH}	RxCLKOut HIGH Time		4.5	5.4	6.5	ns
t _{RSRC}	RxOut Valid Prior to RxCLKOut		3.5	6.3		ns
t _{RHRC}	RxOut Valid After RxCLKOut		3.5	6.5		ns
t _{ROLH}	Output Rise Time (20% to 80%)			2.2	5.0	ns
t _{ROHL}	Output Fall Time (80% to 20%)	C _L =8pF, Figure 9		2.1	5.0	ns
t _{RCCD}	Receiver Clock Input to Clock Output Delay	$\begin{array}{c} T_{A}{=}25^{\circ}C, \ V_{CC}{=}3.3V \\ Figure \ 14^{(\text{Error!}} \\ \text{Reference source not found.}) \end{array}$	3.5	6.9	7.5	ns
t _{RPDD}	Receiver Power-Down Delay	Figure 18			1.0	ms
t _{RSPB0}	Receiver Input Strobe Position of Bit 0		1.00		2.15	ns
t _{RSPB1}	Receiver Input Strobe Position of Bit 1	ut Strobe Position of Bit 1			5.8	ns
t _{RSPB2}	Receiver Input Strobe Position of Bit 2		8.10		9.15	ns
t _{RSPB3}	Receiver Input Strobe Position of Bit 3	sition of Bit 3 f=40MHz			12.6	ns
t _{RSPB4}	Receiver Input Strobe Position of Bit 4		15.1		16.3	ns
t _{RSPB5}	Receiver Input Strobe Position of Bit 5		18.8		19.9	ns
t _{RSPB6}	Receiver Input Strobe Position of Bit 6		22.5		23.6	ns

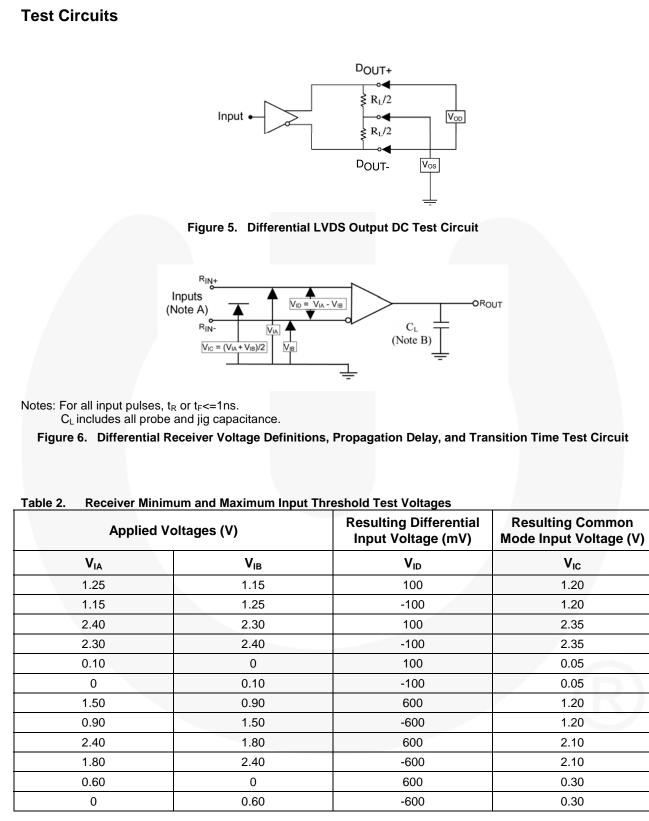
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Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
t _{RSPB0}	Receiver Input Strobe Position of Bit 0		0.7		1.4	ns
t _{RSPB1}	Receiver Input Strobe Position of Bit 1		2.9		3.6	ns
t _{RSPB2}	Receiver Input Strobe Position of Bit 2		5.1		5.8	ns
t _{RSPB3}	Receiver Input Strobe Position of Bit 3	Figure 21 f=65MHz	7.3		8.0	ns
t _{RSPB4}	Receiver Input Strobe Position of Bit 4		9.5		10.2	ns
t _{RSPB5}	Receiver Input Strobe Position of Bit 5		11.7		12.4	ns
t _{RSPB6}	Receiver Input Strobe Position of Bit 6		13.9		14.6	ns
t _{RSPB0}	Receiver Input Strobe Position of Bit 0	Figure 21 f=85MHz FIN1218 only	0.49		1.19	ns
t _{RSPB1}	Receiver Input Strobe Position of Bit 1		2.17		2.87	ns
t _{RSPB2}	Receiver Input Strobe Position of Bit 2		3.85		4.55	ns
t _{RSPB3}	Receiver Input Strobe Position of Bit 3		5.53		6.23	ns
t _{RSPB4}	Receiver Input Strobe Position of Bit 4		7.21		7.91	ns
t _{RSPB5}	Receiver Input Strobe Position of Bit 5		8.89		9.59	ns
t _{RSPB6}	Receiver Input Strobe Position of Bit 6		10.57		11.27	ns
t _{rskm}		f=40MHz, Figure 22	490			ps
	RxIn Skew Margin ^{(Error! Reference source not}	f=65MHz, Figure 22	400			
	found.)	f=85MHz FIN1218 only Figure 22	252			
t _{RPLLS}	Receiver Phase Lock Loop Set Time	Figure 16			10.0	ms

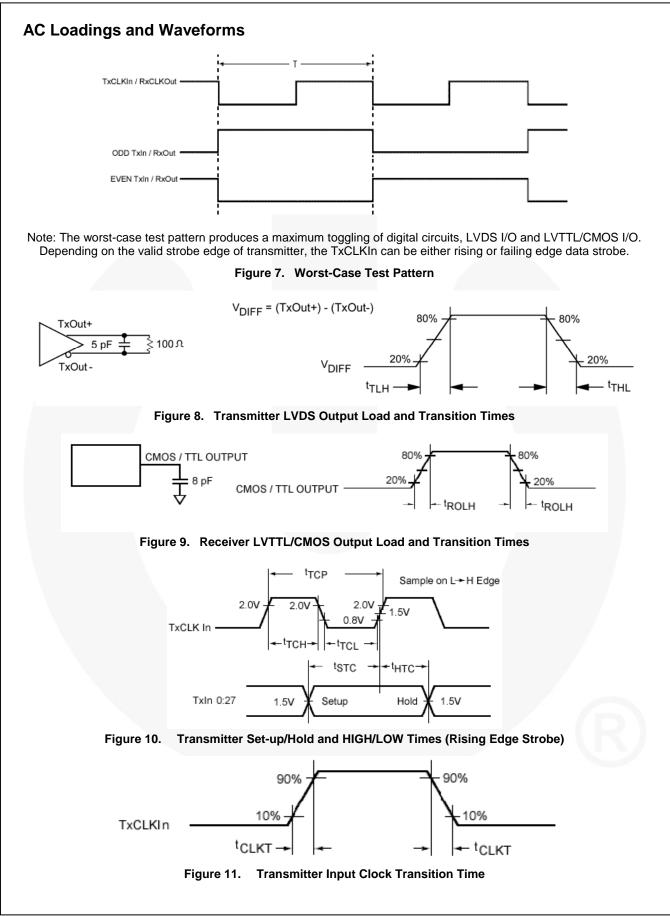
Receiver AC Electrical Characteristics (Continued)

Notes:

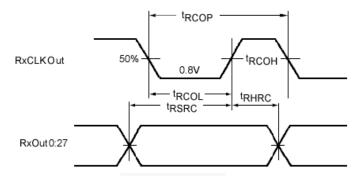
 Total channel latency from serializer to deserializer is (T + t_{TCCD}) + (2•T + t_{RCCD}).
 Receiver skew margin is defined as the valid sampling window after considering potential setup/hold time and minimum/maximum bit position.



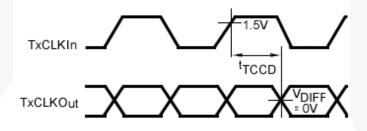
FIN1215 / FIN1216 / FIN1217 — LVDS 21-Bit Serializers / De-Serializers



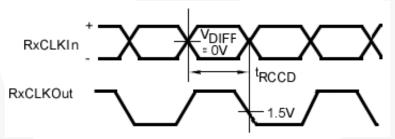
AC Loadings and Waveforms (Continued)



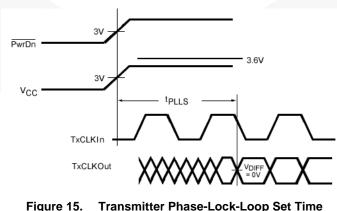




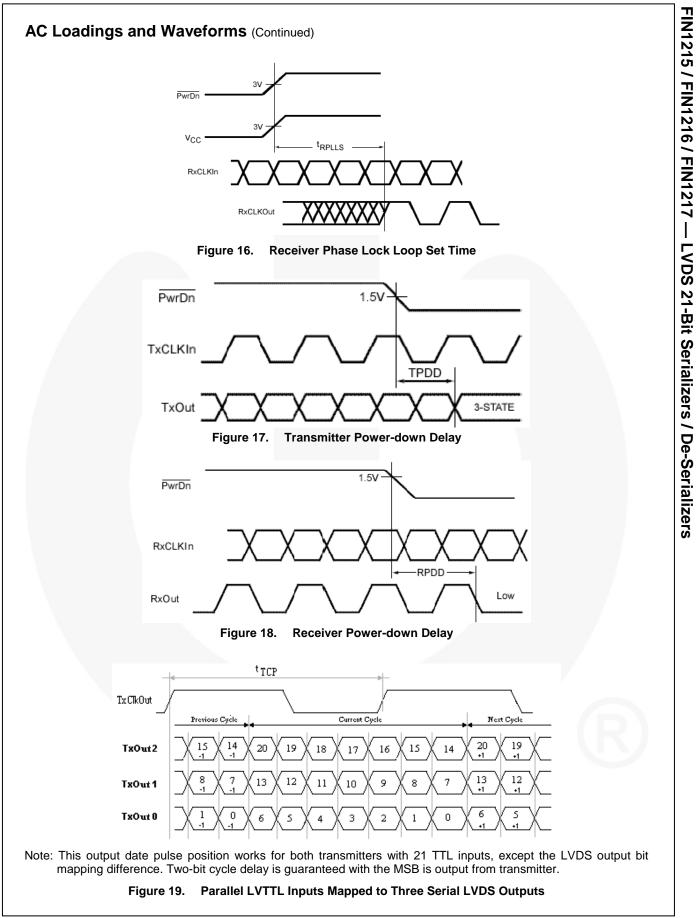


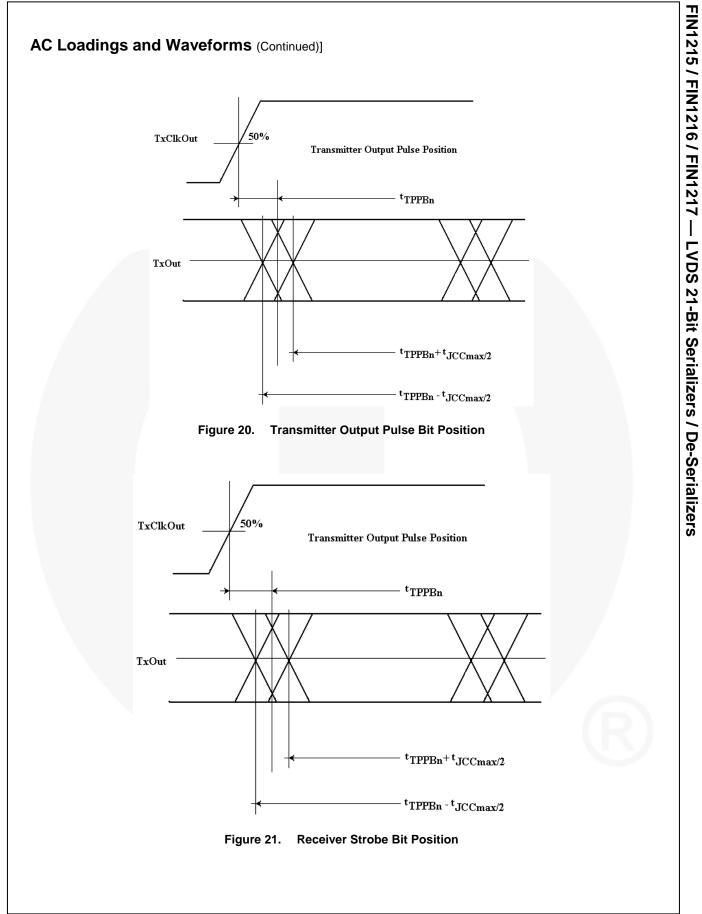


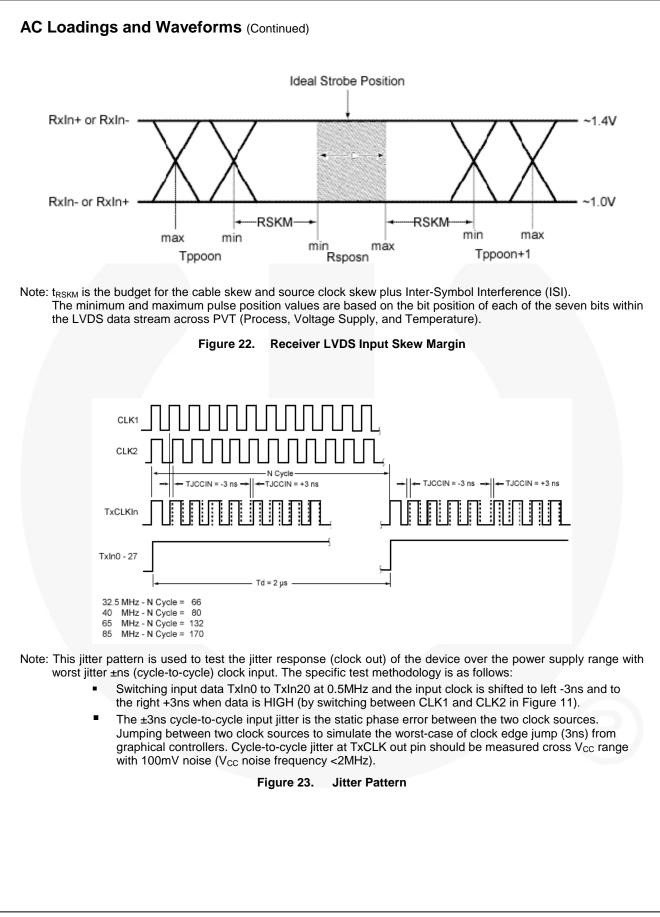
Receiver Clock-In to Clock-Out Delay (Rising Edge Strobe) Figure 14.



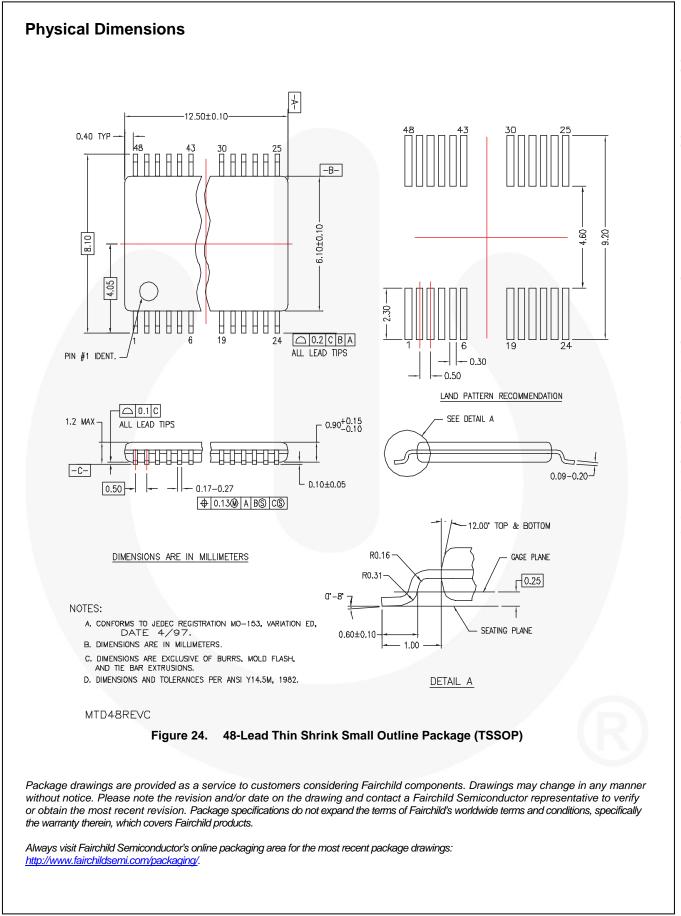


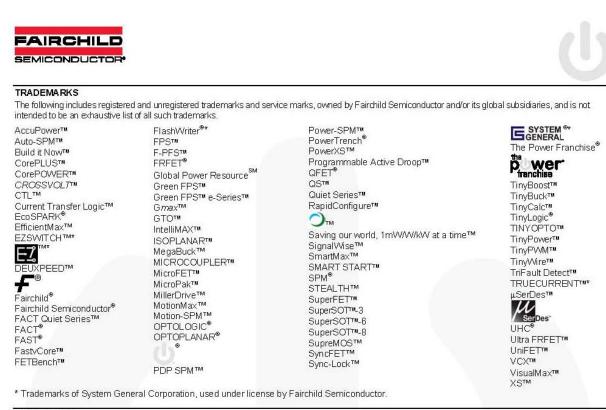






FIN1215 / FIN1216 / FIN1217 — LVDS 21-Bit Serializers / De-Serializers





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